



### **40V DUAL NPN SMALL SIGNAL TRANSISTOR IN SOT563**

### **Features**

- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 200mA High Collector Current
- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Finish; Solderable per MIL-STD-202, Method 208 (a3)
- Weight: 0.003 grams (Approximate)

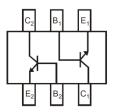
### **SOT563**





**Bottom View** 

Top View



Device Schematic Top View

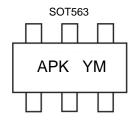
## **Ordering Information (Note 4)**

Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMDT3904VC-7	Active	AEC-Q101	APK	7	8	3000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



 $\begin{array}{l} \text{APK} = \text{Product Type Marking Code} \\ \text{YM} = \text{Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Year (ex: F} = 2018) \\ \text{M or } \overline{\text{M}} = \text{Month (ex: 9} = \text{September)} \end{array}$ 

### Date Code Key

Year	2018		2019	2020		2021	2022		2023	2024		2025
Code	F		G	Н			J		K	L		J
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
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## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current	Ic	200	mA

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\Theta JA}$	833	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

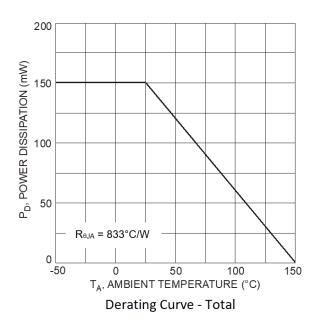
Notes:

<sup>5.</sup> For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristic and Derating Information**





# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

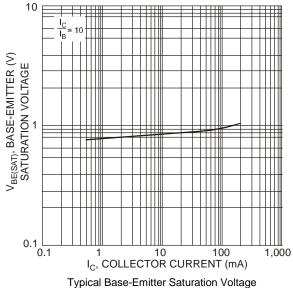
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	_	V	$I_C = 100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	40	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6.0	_	V	$I_E = 100 \mu A, I_C = 0$
Collector-Emitter Cut-Off Current	ICEV	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Emitter-Base Cut-Off Current	I <sub>EBO</sub>	_	50	nA	V <sub>EB</sub> = 6V
ON CHARACTERISTICS (Note 7)					
		40	_		$I_C = 100\mu A, V_{CE} = 1.0V$
		70	_		$I_C = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$
DC Current Gain	h <sub>FE</sub>	100	300	_	$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$
		60	_		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
		30	_		$I_C = 100 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.20 0.30	V	$I_C = 10mA, I_B = 1.0mA$
Concotor Entities Catalation Voltage	VCE(SAT)				$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.65	0.85	V	$I_C = 10mA, I_B = 1.0mA$
	VBE(SAT)	_	0.95	•	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS			1	1	
Output Capacitance	C <sub>OBO</sub>		4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>IBO</sub>	_	8.0	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	h <sub>ie</sub>	1.0	10	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.5	8.0	× 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h <sub>fe</sub>	100	400	_	f = 1.0kHz
Output Admittance	h <sub>oe</sub>	1.0	40	μS	
Current Gain-Bandwidth Product	f⊤	300	_	MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz
Noise Figure	NF	_	5.0	dB	$V_{CE} = 5.0V$ , $I_{C} = 100\mu A$ , $R_{S} = 1.0k\Omega$ , $f = 1.0kHz$
SWITCHING CHARACTERISTICS			<u> </u>		11.5 - 1.01.22, 1 - 1.01.12
Delay Time	t <sub>d</sub>		35	ns	V <sub>CC</sub> = 3.0V, I <sub>C</sub> = 10mA,
Rise Time	t <sub>r</sub>		35	ns	$V_{BE(OFF)} = -0.5V, I_{B1} = 1.0mA$
Storage Time	t <sub>s</sub>		200	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Fall Time	t <sub>f</sub>		50	ns	$I_{B1} = -I_{B2} = 1.0 \text{mA}$
	ч			110	101 102 - 11011171

Note:

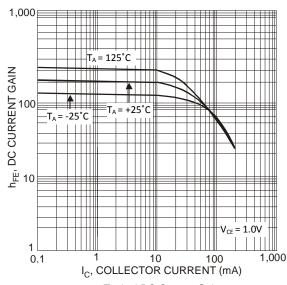
<sup>7.</sup> Measured under pulsed conditions. Pulse width  $\leq 300 \mu s.$  Duty cycle  $\leq 2\%.$ 



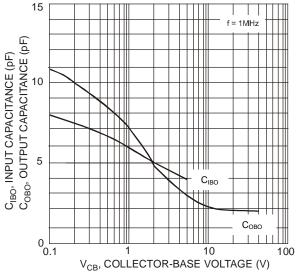
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



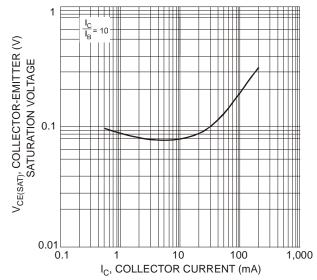
Typical Base-Emitter Saturation Voltage vs. Collector Current



Typical DC Current Gain vs. Collector Current



Input and Output Capacitance vs. Collector-Base Voltage

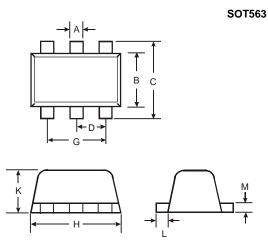


Typical Collector-Emitter Saturation Voltage vs. Collector Current



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

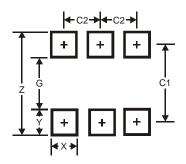


SOT563						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.20			
В	1.10	1.25	1.20			
С	1.55	1.70	1.60			
D	-	-	0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
K	0.55	0.60	0.60			
L	0.10	0.30	0.20			
М	0.10	0.18	0.11			
All	All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT563



Dimensions	SOT563
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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